

Features

- 650 V, 50 A, Low Collector-Emitter Saturation Voltage (V_{CE(sat)})
- Trench-Gate Field-Stop technology
- Optimized for conduction
- RoHS compliant*

Applications

- Switch-Mode Power Supplies (SMPS)
- Uninterruptible Power Sources (UPS)
- Power Factor Correction (PFC)
- Inverters

BIDW50N65T Insulated Gate Bipolar Transistor (IGBT)

General Information

The Bourns® Model BIDW50N65T IGBT device combines technology from a MOS gate and a bipolar transistor for an optimum component for high voltage and high current applications. This device uses Trench-Gate Field-Stop technology providing greater control of dynamic characteristics with a lower Collector-Emitter Saturation Voltage (V_{CE(sat)}) and fewer switching losses. In addition, this structure provides a lower thermal resistance R_(th).

Additional Information

Click these links for more information:



Maximum Electrical Ratings (T_C = 25 °C, unless otherwise specified)

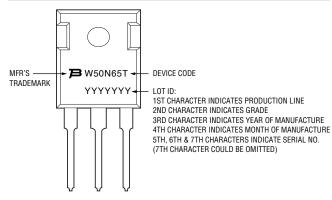
Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CES}	650	V
Continuous Collector Current (T _C = 25 °C), limited by T_{jmax}	Ι _C	100	А
Continuous Collector Current (T _C = 100 °C), limited by T_{jmax}	Ι _C	50	А
Pulsed Collector Current, tp limited by Tjmax	I _{CP}	150	А
Gate-Emitter Voltage	V _{GE}	±20	V
Continuous Forward Current (T _C = 100 °C), limited by T _{jmax}	l _F	50	А
Short-circuit Withstand Time (V_{CE} = 300 V, V_{GE} = 15 V)	T _{SC}	10	μs
Total Power Dissipation	P _{total}	416	W
Storage Temperature	T _{STG}	-55 to +150	°C
Operating Junction Temperature	Tj	-55 to +150	°C

Thermal Resistance

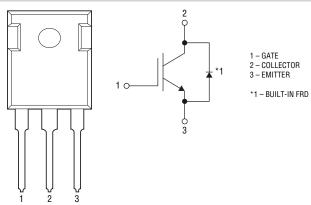
Parameter	Symbol	Мах	Unit
IGBT Thermal Resistance Junction - Case	R _{th(j-c)_IGBT}	0.3	°C/W
Diode Thermal Resistance Junction - Case	R _{th(j-c)_Diode}	0.65	°C/W

Typical Part Marking

Reproductive Harm



Internal Circuit



*RoHS Directive 2015/863, Mar 31, 2015 and Annex. Specifications are subject to change without notice. WARNING Cancer and

Users should verify actual device performance in their specific applications.

BOURNS®

Static Electrical Characteristics (T_C = 25 °C, Unless Otherwise Specified)

Parameter	Symbol	Conditions	Value			Unit	
Farameter	Symbol	Conditions	Min.	Тур.	Max.	onit	
Collector-Emitter Breakdown Voltage	BV _{CES}	V_{GE} = 0 V, I_C = 250 μ A	650	—	—	V	
Collector Emitter Seturation Veltage	N	V_{GE} = 15 V, I _C = 50 A T _C = 25 °C	_	1.65	2.2	v	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$V_{GE} = 15 \text{ V}, I_{C} = 50 \text{ A}$ $T_{C} = 125 \text{ °C}$	_	1.9	_		
		I _F = 50 A, T _C = 25 °C	_	1.7	2.5	V	
Diode Forward On-Voltage	V _F	I _F = 50 A, T _C = 125 °C	_	1.3	_	V	
Gate Threshold Voltage	V _{GE(th)}	$V_{CE} = V_{GE}, I_C = 250 \ \mu A$	4.0	5.0	7.0	V	
Collector Cut-off Current	I _{CES}	V _{GE} = 0 V, V _{CE} = 650 V	_	_	200	μA	
Gate-Emitter Leakage Current	I _{GES}	$V_{CE} = 0 V, V_{GE} = \pm 20 V$	_	_	±400	nA	

Dynamic Electrical Characteristics (T_C = 25 °C, Unless Otherwise Specified)

Parameter	Symbol Conditions		Value			11
		Min.	Тур.	Max.	Unit	
Input Capacitance	C _{ies}		_	2723	_	
Output Capacitance	C _{oes}	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	_	230	_	pF
Reverse Transfer Capacitance	C _{res}	1 - 1 10112	_	55	_	
Total Gate Charge	Qg	$V_{CE} = 400 \text{ V}, V_{GE} = 15 \text{ V}$ $I_{C} = 50.0 \text{ A}$	_	123	_	
Gate-Emitter Charge	Q _{ge}		_	31	_	nC
Gate-Collector Charge	Q _{gc}		_	48	_	

IGBT Switching Characteristics (Inductive Load, T_C = 25 °C, unless otherwise specified)

Parameter	Cumbel	Conditions	Value			11
	Symbol	Symbol Conditions	Min.	Тур.	Max.	Unit
Turn-on Delay Time	t _{d(on)}		_	37	_	ns
Current Rise Time	t _r		_	133	_	ns
Turn-off Delay Time	t _{d(off)}	$V_{CE} = 400$ V, $V_{GE} = 15$ V I _C = 50.0 A, R _G = 10 Ω	_	125	_	ns
Current Fall Time	t _f		_	121	_	ns
Turn-on Switching Energy	Eon		_	3.0	_	mJ
Turn-off Switching Energy	E _{off}		_	1.1	_	mJ
Total Switching Energy	E _{ts}		_	4.1	_	mJ

Specifications are subject to change without notice.

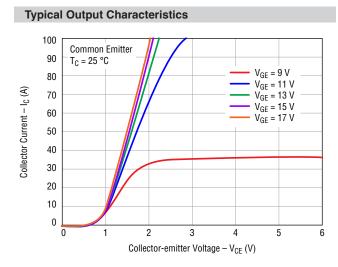
Users should verify actual device performance in their specific applications. The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at <u>www.bourns.com/docs/legal/disclaimer.pdf</u>.

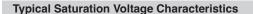
BOURNS

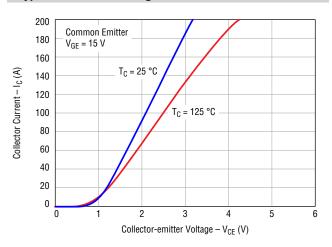
Diode Switching Characteristics (T_C = 25 °C, unless otherwise specified)

Parameter	Symbol Conditions	Conditions	Value			Unit
Parameter		Conditions	Min.	Тур.	Max.	Unit
Reverse Recovery Time	t _{rr}	dl _F /dt = 200 A/µs	—	37.5	_	ns
Reverse Recovery Charge	Q _{rr}	I _F = 50.0 A	—	78	_	nC

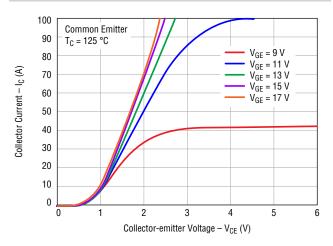
Electrical Characteristic Performance



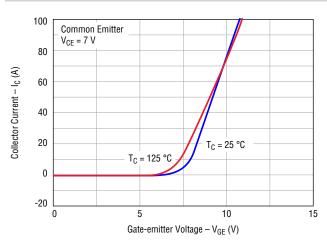




Typical Output Characteristics



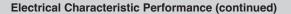
Typical Transfer Characteristics



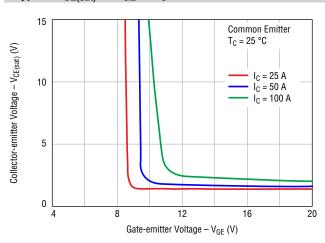
Specifications are subject to change without notice.

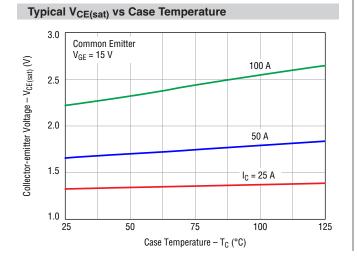
Users should verify actual device performance in their specific applications.

BOURNS

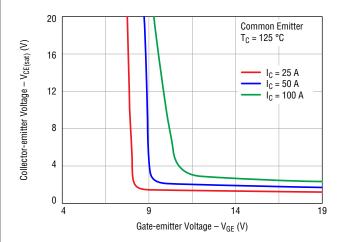


Typical V_{CE(sat)} vs V_{GE} @ T_C = 25 °C

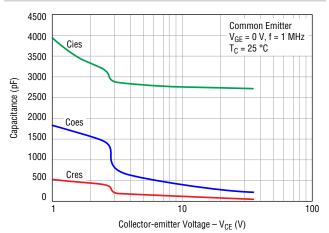




Typical V_{CE(sat)} vs V_{GE} @ T_C = 125 °C



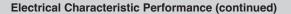
Typical Capacitance Characteristics

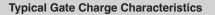


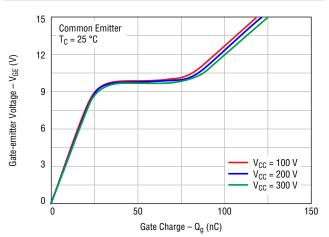
Specifications are subject to change without notice.

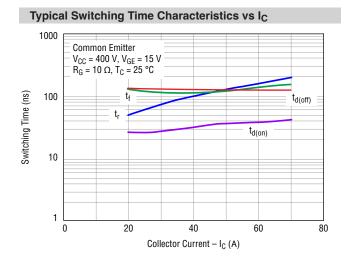
Users should verify actual device performance in their specific applications.

BOURNS



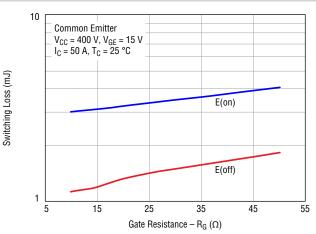






1000 t_{d(off)} Switching Time (ns) tr 100 t_f t_{d(on)} Common Emitter $V_{CC} = 400 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$ $I_C = 50 \text{ A}, \text{ T}_C = 25 \text{ °C}$ 10 15 25 35 45 55 5 Gate Resistance – $R_G(\Omega)$



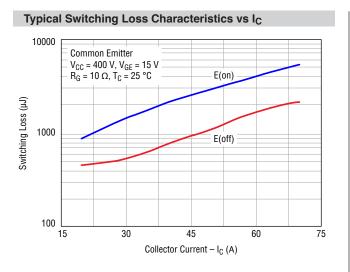


Typical Switching Time Characteristics vs $\ensuremath{\mathsf{R}_{\mathsf{G}}}$

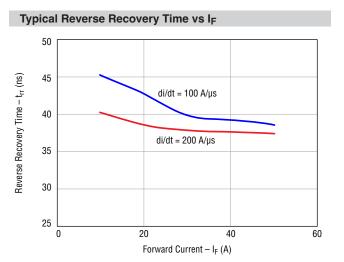
Specifications are subject to change without notice.

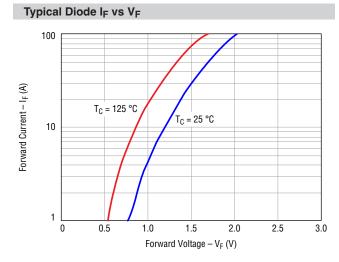
Users should verify actual device performance in their specific applications.

BOURNS

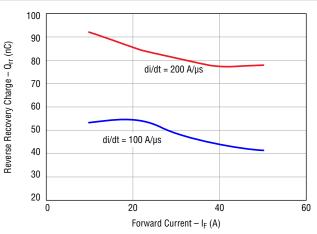


Electrical Characteristic Performance (continued)





Typical Reverse Recovery Charge vs I_F



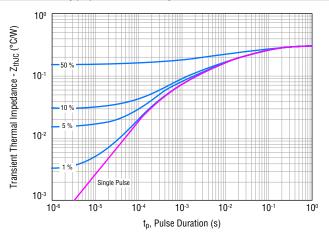
Specifications are subject to change without notice.

Users should verify actual device performance in their specific applications.

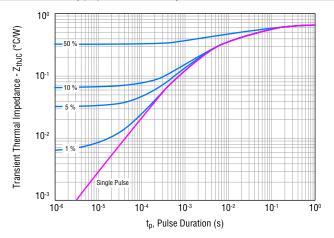
BOURNS

Electrical Characteristic Performance (continued)

IGBT Transient Thermal Impedance vs tp(on) Duration (D=tp/T)



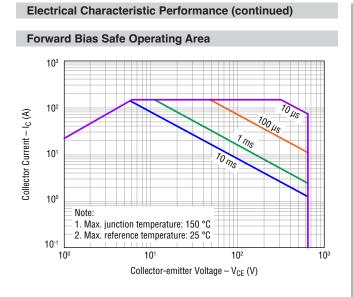
Diode Transient Thermal Impedance vs $t_{p(on)}$ Duration (D= t_p/T)

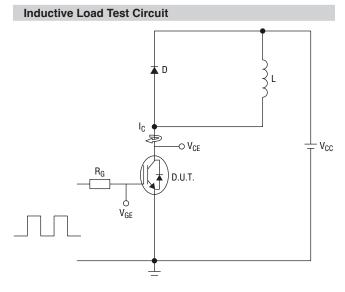


Specifications are subject to change without notice.

Users should verify actual device performance in their specific applications. The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at <u>www.bourns.com/docs/legal/disclaimer.pdf</u>.

BOURNS





How to Order B I D W 50 N 65 T B = Bourns® I = IGBT · Туре D = Discrete Package Code W = TO-247-3L Current Rating 50 = 50 A Device Type -N = N-channel Nominal Voltage (divided by 10) -65 = 650 Ŭ Optimization -T = Medium Speed

Environmental Characteristics

ESD Class (H	1BM)	2

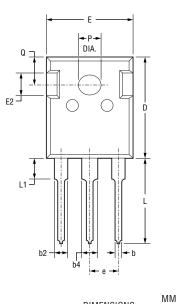
L = 1.12 mH, V_{CE} = 400 V, V_{GE} = 15 V, I_{C} = 50 A, R_G = 10 Ω

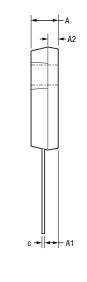
Specifications are subject to change without notice.

Users should verify actual device performance in their specific applications.

BOURNS®

Product Dimensions





DIMENSIONS: $\frac{MM}{(INCHES)}$

Packaging Specifications

BIDW50N65T 30 pieces per tube

Symbol	Min.	Nom.	Max.
A	<u>4.80</u> (.189)	<u>5.00</u> (.197)	<u>5.20</u> (.205)
A1	<u>2.21</u> (.087)	<u>2.41</u> (.095)	<u>2.59</u> (.102)
A2	<u>1.85</u> (.073)	<u>2.00</u> (.079)	<u>2.15</u> (.085)
b	<u>1.11</u> (.044)	_	<u>1.36</u> (.054)
b2	<u>1.91</u> (.075)	_	<u>2.25</u> (.089)
b4	<u>2.91</u> (.115)	_	<u>3.25</u> (.128)
с	<u>0.51</u> (.020)	_	<u>0.75</u> (.030)
D	<u>20.80</u> (.819)	<u>21.00</u> (.827)	<u>21.30</u> (.839)
E	<u>15.50</u> (.610)	<u>15.80</u> (.622)	<u>16.10</u> (.634)
E2	<u>4.40</u> (.173)	<u>5.00</u> (.197)	<u>5.20</u> (.205)
е		<u>5.44</u> (.214) BSC	
L	<u>19.72</u> (.776)	<u>19.92</u> (.784)	<u>20.22</u> (.796)
L1	_	_	<u>4.30</u> (.169)
Р	<u>3.40</u> (.134)	_	<u>3.80</u> (.150)
Q	$\frac{5.60}{(.220)}$	$\frac{5.80}{(.228)}$	<u>6.00</u> (.236)

BOURNS

Asia-Pacific: Tel: +886-2 2562-4117 Email: asiacus@bourns.com EMEA: Tel: +36 88 885 877 Email: eurocus@bourns.com

The Americas: Tel: +1-951 781-5500 Email: americus@bourns.com

www.bourns.com

07/22

Specifications are subject to change without notice.

Users should verify actual device performance in their specific applications.

Legal Disclaimer Notice

This legal disclaimer applies to purchasers and users of Bourns[®] products manufactured by or on behalf of Bourns, Inc. and its affiliates (collectively, "Bourns").

Unless otherwise expressly indicated in writing, Bourns[®] products and data sheets relating thereto are subject to change without notice. Users should check for and obtain the latest relevant information and verify that such information is current and complete before placing orders for Bourns[®] products.

The characteristics and parameters of a Bourns[®] product set forth in its data sheet are based on laboratory conditions, and statements regarding the suitability of products for certain types of applications are based on Bourns' knowledge of typical requirements in generic applications. The characteristics and parameters of a Bourns[®] product in a user application may vary from the data sheet characteristics and parameters due to (i) the combination of the Bourns[®] product with other components in the user's application, or (ii) the environment of the user application itself. The characteristics and parameters of a Bourns[®] product with other components of a Bourns[®] product also can and do vary in different applications and actual performance may vary over time. Users should always verify the actual performance of the Bourns[®] product in their specific devices and applications, and make their own independent judgments regarding the amount of additional test margin to design into their device or application to compensate for differences between laboratory and real world conditions.

Unless Bourns has explicitly designated an individual Bourns[®] product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949) or a particular qualification (e.g., UL listed or recognized), Bourns is not responsible for any failure of an individual Bourns[®] product to meet the requirements of such industry standard or particular qualification. Users of Bourns[®] products are responsible for ensuring compliance with safety-related requirements and standards applicable to their devices or applications.

Bourns[®] products are not recommended, authorized or intended for use in nuclear, lifesaving, life-critical or life-sustaining applications, nor in any other applications where failure or malfunction may result in personal injury, death, or severe property or environmental damage. Unless expressly and specifically approved in writing by two authorized Bourns representatives on a case-by-case basis, use of any Bourns[®] products in such unauthorized applications might not be safe and thus is at the user's sole risk. Life-critical applications include devices identified by the U.S. Food and Drug Administration as Class III devices and generally equivalent classifications outside of the United States.

Bourns expressly identifies those Bourns[®] standard products that are suitable for use in automotive applications on such products' data sheets in the section entitled "Applications." Unless expressly and specifically approved in writing by two authorized Bourns representatives on a case-by-case basis, use of any other Bourns[®] standard products in an automotive application might not be safe and thus is not recommended, authorized or intended and is at the user's sole risk. If Bourns expressly identifies a sub-category of automotive application in the data sheet for its standard products (such as infotainment or lighting), such identification means that Bourns has reviewed its standard product and has determined that if such Bourns[®] standard product is considered for potential use in automotive applications, it should only be used in such sub-category of automotive applications. Any reference to Bourns[®] standard product in the data sheet as compliant with the AEC-Q standard or "automotive grade" does not by itself mean that Bourns has approved such product for use in an automotive application.

Bourns[®] standard products are not tested to comply with United States Federal Aviation Administration standards generally or any other generally equivalent governmental organization standard applicable to products designed or manufactured for use in aircraft or space applications. Bourns expressly identifies Bourns[®] standard products that are suitable for use in aircraft or space applications on such products' data sheets in the section entitled "Applications." Unless expressly and specifically approved in writing by two authorized Bourns representatives on a case-by-case basis, use of any other Bourns[®] standard product in an aircraft or space application might not be safe and thus is not recommended, authorized or intended and is at the user's sole risk.

The use and level of testing applicable to Bourns[®] custom products shall be negotiated on a case-by-case basis by Bourns and the user for which such Bourns[®] custom products are specially designed. Absent a written agreement between Bourns and the user regarding the use and level of such testing, the above provisions applicable to Bourns[®] standard products shall also apply to such Bourns[®] custom products.

Users shall not sell, transfer, export or re-export any Bourns[®] products or technology for use in activities which involve the design, development, production, use or stockpiling of nuclear, chemical or biological weapons or missiles, nor shall they use Bourns[®] products or technology in any facility which engages in activities relating to such devices. The foregoing restrictions apply to all uses and applications that violate national or international prohibitions, including embargos or international regulations. Further, Bourns[®] products and Bourns technology and technical data may not under any circumstance be exported or re-exported to countries subject to international sanctions or embargoes. Bourns[®] products may not, without prior authorization from Bourns and/or the U.S. Government, be resold, transferred, or re-exported to any party not eligible to receive U.S. commodities, software, and technical data.

To the maximum extent permitted by applicable law, Bourns disclaims (i) any and all liability for special, punitive, consequential, incidental or indirect damages or lost revenues or lost profits, and (ii) any and all implied warranties, including implied warranties of fitness for particular purpose, non-infringement and merchantability.

For your convenience, copies of this Legal Disclaimer Notice with German, Spanish, Japanese, Traditional Chinese and Simplified Chinese bilingual versions are available at:

Web Page: <u>http://www.bourns.com/legal/disclaimers-terms-and-policies</u> PDF: <u>http://www.bourns.com/docs/Legal/disclaimer.pdf</u>

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for IGBT Transistors category:

Click to view products by Bourns manufacturer:

Other Similar products are found below :

748152A APT20GT60BRDQ1G IGW40N60H3FKSA1 STGFW20V60DF APT45GR65B2DU30 GT50JR22(STA1ES) TIG058E8-TL-H IGW40N120H3FKSA1 VS-CPV364M4KPBF NGTB25N120FL2WAG NGTG40N120FL2WG RJH60F3DPQ-A0#T0 APT40GR120B2SCD10 APT15GT120BRG NGTB75N65FL2WAG NGTG15N120FL2WG APT70GR65B2DU40 NTE3320 GPU75HF120D1SE GPU200HF120D2SE KWRFF75R12SWM KWFFP10R12NS3 MG100UZ12MRGJ-A2-0000 IHFW40N65R5SXKSA1 IKFW50N65ES5XKSA1 IKFW50N65EH5XKSA1 IKFW40N65ES5XKSA1 IKFW60N65ES5XKSA1 IMBG120R140M1HXTMA1 XP15PJS120CL1B1 IGW30N60H3FKSA1 STGWA8M120DF3 IGW08T120FKSA1 IGB30N60H3ATMA1 IGW100N60H3FKSA1 IGW75N60H3FKSA1 SGM40HF12A1TFD CRGMF50T120FSC CRGMF100T120FSA3 CRGMF75T120FSC LEGM200BA120L2H IXYK110N120C4 FGHL50T65MQDT IXYH55N120C4 IXYX110N120B4 IXYK110N120B4 IXBH20N360HV BIDNW30N60H3 VS-GT90SA120U BIDW20N60T